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<b>Form 1449 (Modified)</b>  <b>Information Disclosure Statement By Applicant</b>  (Use Several Sheets if Necessary)	Atty Docket No.	Application No.:
	LAM1P147/P0675	09/782,185
	Applicant:	
	ZHU et al.	
	Filing Date	Group
	February 12, 2001	3765

**U.S. Patent Documents**

Examiner Initial	No.	Patent No.	Date	Patentee	Class	Sub-class	Filing Date
	A						
	B						
	C						
	D						
	E						
	F						
	G						
	H						
	I						

**Foreign Patent or Published Foreign Patent Application**

Examiner Initial	No.	Document No.	Publication Date	Country or Patent Office	Class	Sub-class	Translation	
							Yes	No
	J							
	K							
	L							
	M							
	N							

**Other Documents**

Examiner Initial	No.	Author, Title, Date, Place (e.g. Journal) of Publication
K-cc	O	U.S. Patent Application Serial No. 09/782,678, entitled "Post-Etch Photoresist Strip with O2 and NH3 for Organosilicate Glass Low-K Dielectric Etch Applications", filed February 12, 2001
K-cc	P	U.S. Patent Application Serial No. 09/782,446, entitled "Use of Ammonia for Etching Organic Low-K Dielectrics", filed February 12, 2001
K-cc	Q	U.S. Patent Application Serial No. 09/782,437, entitled "Use of Hydrocarbon Addition for the Elimination of Micromasking during Etching of Organic Low-K Dielectrics", filed February 12, 2001
Examiner <i>Kin-CL CHEN</i>		Date Considered <i>02-19-02</i>

Examiner: Initial citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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